



Parameter	Ratings	Units
Blocking Voltage	100	V_p
Load Current	300	mA_{rms} / mA_{DC}
On-Resistance (max)	8	Ω

Features

- 3750V_{rms} Input/Output Isolation
- Low Drive Power Requirements (TTL/CMOS Compatible)
- High Reliability
- Arc-Free With No Snubbing Circuits
- FCC Compatible
- VDE Compatible
- No EMI/RFI Generation
- Small 8-Pin Package
- Machine Insertable, Wave Solderable
- Surface Mount Tape & Reel Versions Available

Applications

- Instrumentation
 - Multiplexers
 - Data Acquisition
 - Electronic Switching
 - I/O Subsystems
- Meters (Watt-Hour, Water, Gas)
- Medical Equipment-Patient/Equipment Isolation
- Security
- Aerospace
- Industrial Controls

Description

IXYS Integrated Circuits Division's LAA108 is a 100V, 300mA, 8 Ω dual single-pole, normally open (1-Form-A) Solid State Relay that has two independently controlled, optically coupled outputs. The output MOSFET switches and photovoltaic die employ optically coupled MOSFET technology to provide 3750 V_{rms} of input-to-output isolation.

The relay outputs, that use patented OptoMOS architecture, are controlled by a highly efficient GaAlAs infrared LED.

This dual single-pole OptoMOS relay provides a more compact design solution than two discrete single-pole relays in a variety of applications, saving board space by incorporating both switches in a single 8-Pin package.

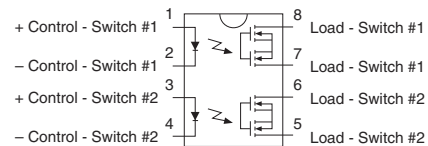
Approvals

- UL Certified Component: File E76270
- CSA Certified Component: Certificate 1175739
- EN/IEC 60950-1 Certified Component: TUV Certificate B 10 05 49410 006

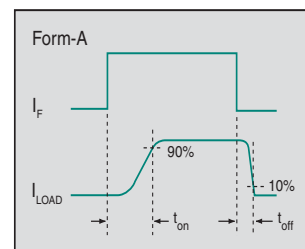
Ordering Information

Part #	Description
LAA108	8-Pin DIP (50/Tube)
LAA108S	8-Pin Surface Mount (50/Tube)
LAA108STR	8-Pin Surface Mount (1,000/Reel)
LAA108P	8-Pin Flat Pack (50/Tube)
LAA108PTR	8-Pin Flat Pack (1,000/Reel)

Pin Configuration



Switching Characteristics of Normally Open (Form A) Devices



Absolute Maximum Ratings @ 25°C

Parameter	Ratings	Units
Blocking Voltage	100	V _P
Reverse Input Voltage	5	V
Input Control Current	50	mA
Peak (10ms)	1	A
Input Power Dissipation ¹	150	mW
Total Power Dissipation ²	800	mW
Isolation Voltage, Input to Output	3750	V _{rms}
Operational Temperature	-40 to +85	°C
Storage Temperature	-40 to +125	°C

¹ Derate linearly 1.33 mW / °C
² Derate linearly 6.67 mW / °C

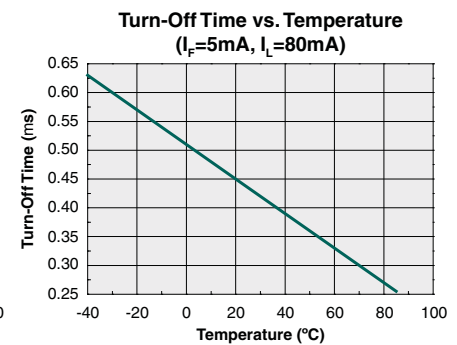
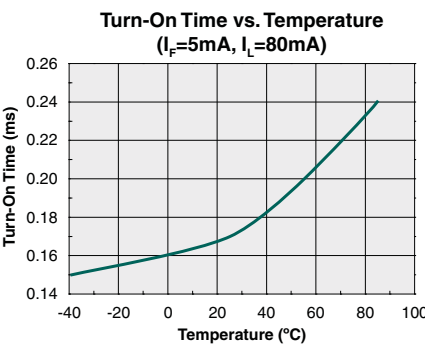
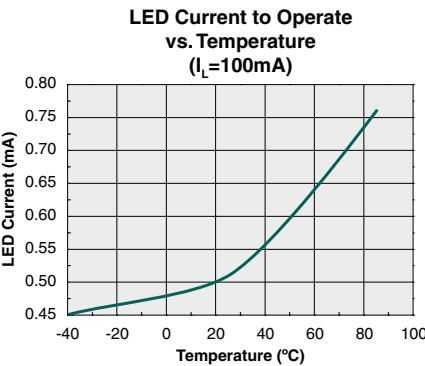
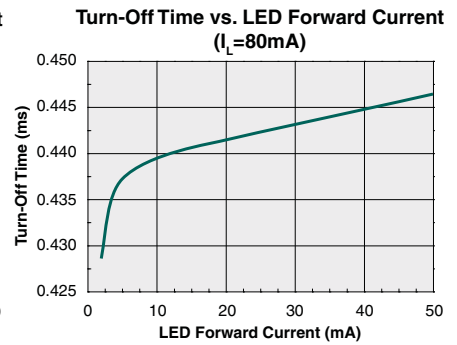
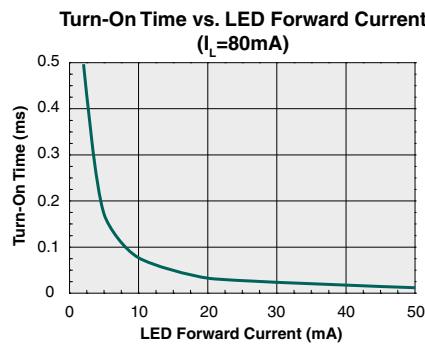
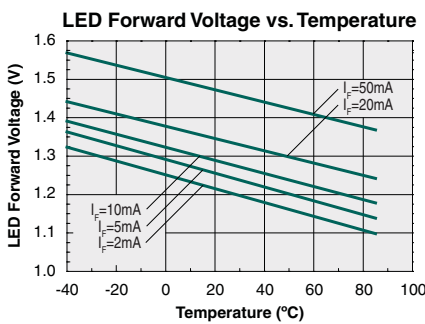
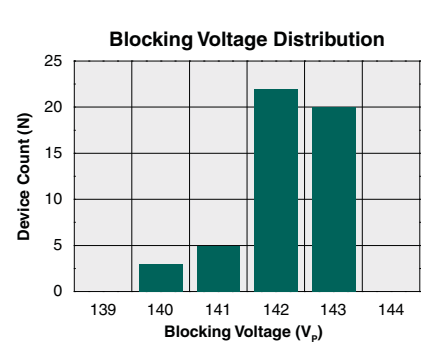
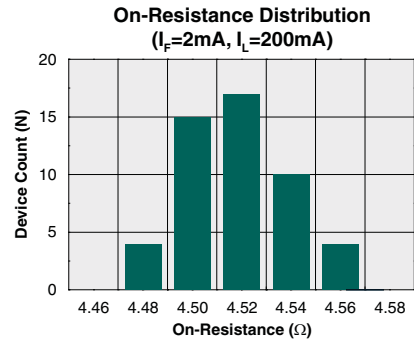
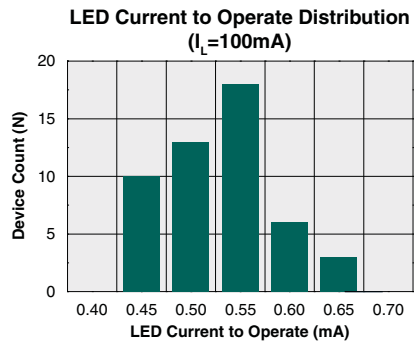
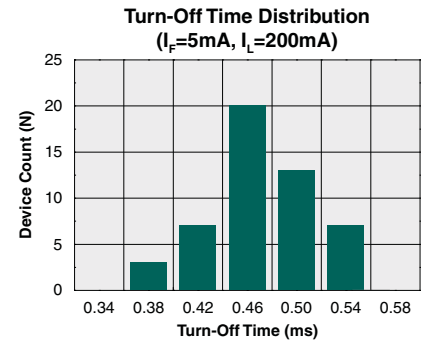
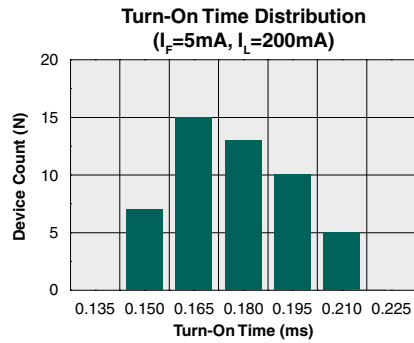
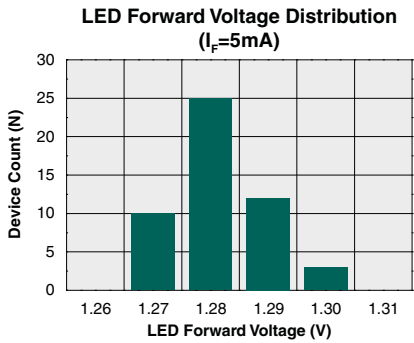
Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

Electrical Characteristics @ 25°C (Unless Otherwise Noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Units
Output Characteristics						
Load Current						
Continuous ¹	-	I _L	-	-	300	mA _{rms} / mA _{DC}
Peak	t = 10ms	I _{LPK}	-	-	±400	mA _P
On-Resistance ²	I _L = 300mA	R _{ON}	-	4.5	8	Ω
Off-State Leakage Current	V _L = 100V _P	I _{LEAK}	-	-	1	μA
Switching Speeds						
Turn-On	I _F = 5mA, V _L = 10V	t _{on}	-	0.43	3	ms
Turn-Off		t _{off}	-	0.17	3	
Output Capacitance	V _L = 50V, f = 1MHz	C _{OUT}	-	110	-	pF
Input Characteristics						
Input Control Current to Activate ³	I _L = 300mA	I _F	-	0.5	2	mA
Input Control Current to Deactivate	-	-	0.2	0.3	-	mA
Input Voltage Drop	I _F = 5mA	V _F	0.9	1.2	1.4	V
Reverse Input Current	V _R = 5V	I _R	-	-	10	μA
Common Characteristics						
Input to Output Capacitance	-	C _{VO}	-	3	-	pF

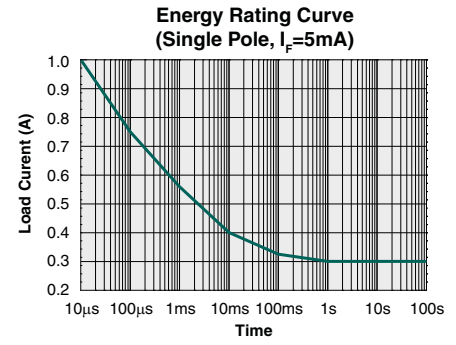
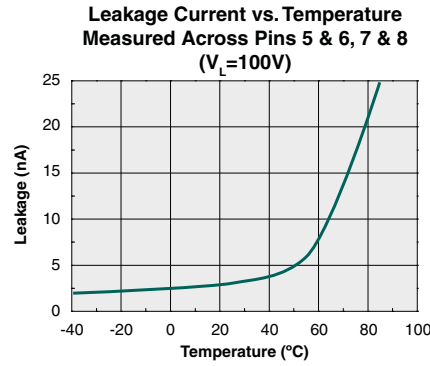
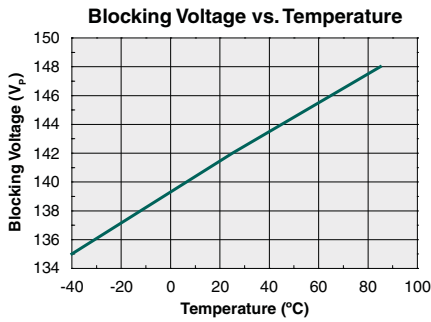
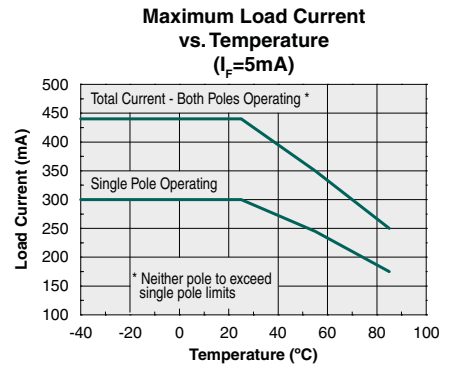
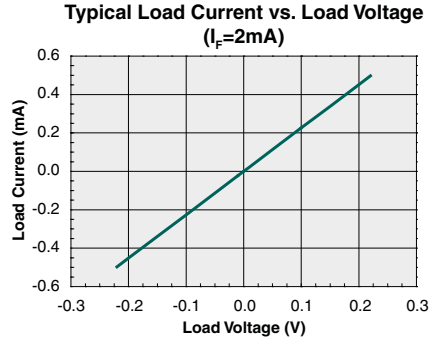
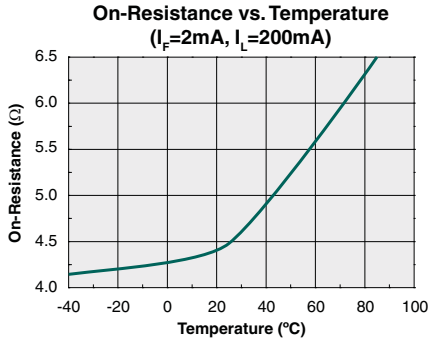
¹ If both poles operate simultaneously, the load current must be derated so as not to exceed the package total power dissipation value.
² Measurement taken within one (1) second of on-time.
³ For applications requiring high-temperature operation (T > 60°C), a LED drive current of 4mA is recommended.

PERFORMANCE DATA @ 25°C (Unless Otherwise Noted)*



*The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

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Manufacturing Information

Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. IXYS Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL) rating** as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Rating
LAA108 / LAA108S / LAA108P	MSL 1

ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

Reflow Profile

This product has a maximum body temperature and time rating as shown below. All other guidelines of **J-STD-020** must be observed.

Device	Maximum Temperature x Time
LAA108 / LAA108S	250°C for 30 seconds
LAA108P	260°C for 30 seconds

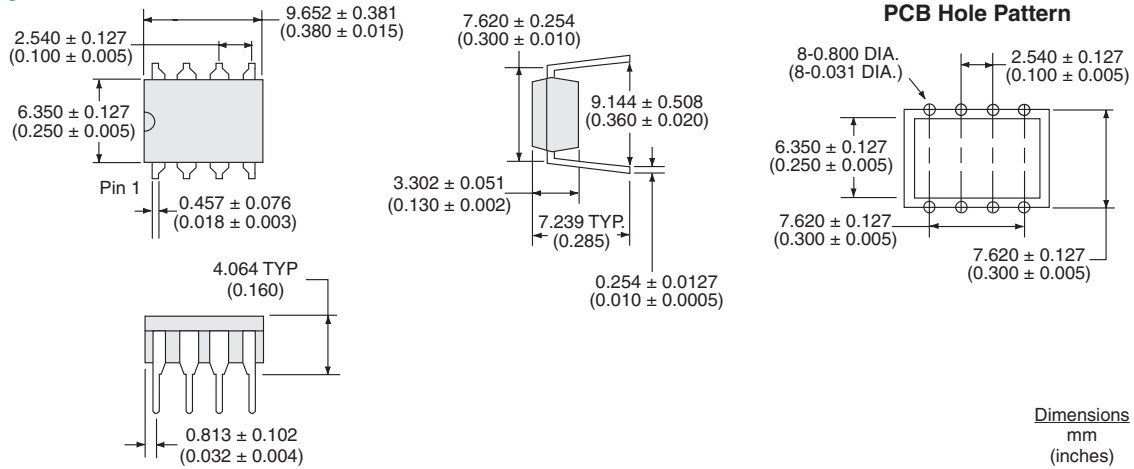
Board Wash

IXYS Integrated Circuits Division recommends the use of no-clean flux formulations. However, board washing to remove flux residue is acceptable. Since IXYS Integrated Circuits Division employs the use of silicone coating as an optical waveguide in many of its optically isolated products, the use of a short drying bake could be necessary if a wash is used after solder reflow processes. Chlorine- or Fluorine-based solvents or fluxes should not be used. Cleaning methods that employ ultrasonic energy should not be used.

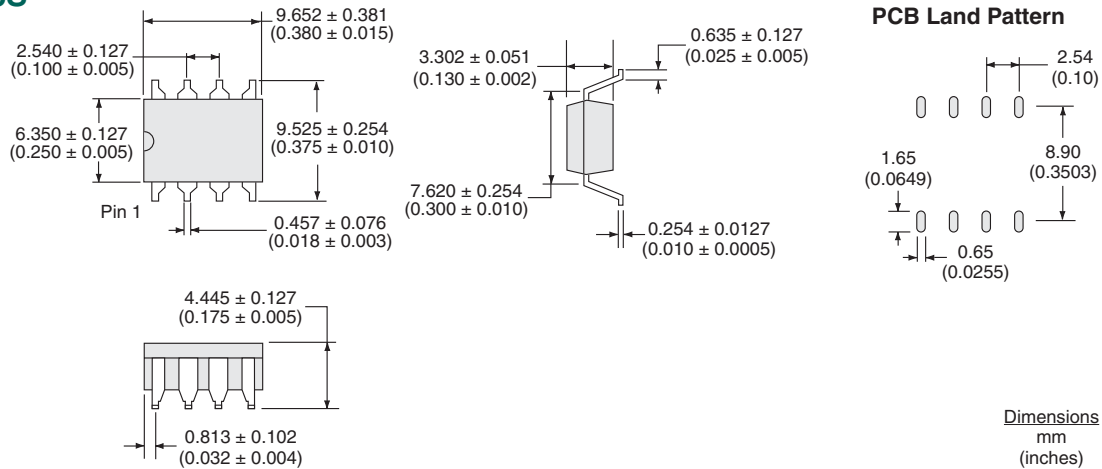


MECHANICAL DIMENSIONS

LAA108



LAA108S



LAA108P

